

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1432	438/197.ccls. or 438/238.ccls.	USPAT	OR	ON	2005/01/06 19:09
S2	692	438/239.ccls.	USPAT	OR	ON	2005/01/06 19:10
S3	1787	438/253.ccls.	USPAT	OR	ON	2005/01/06 19:10
S4	1785	438/396.ccls.	USPAT	OR	ON	2005/01/06 19:10
S5	4096	S1 or S2 or S3 or S4	USPAT	OR	ON	2005/01/06 19:12
S6	1167	S5 and (capacitor and (MOS or (metal adj oxide adj semiconductor)) and (etch\$3 or implant\$3))	USPAT	OR	ON	2005/01/06 21:13
S7	909	S6 and mask	USPAT	OR	ON	2005/01/06 19:14
S8	12	S7 and (mixed-mode or (mixed adj mode))	USPAT	OR	ON	2005/01/06 20:59
S9	2237	S5 and (reduc\$4 with (size or thickness or dimension or area or length or height or width))	USPAT	OR	ON	2005/01/06 21:00
S10	300	S5 and ((reduc\$4 with (size or thickness or dimension or area or length or height or width)) with etch\$3)	USPAT	OR	ON	2005/01/06 21:03
S11	18519	(capacitor and (MOS or (metal adj oxide adj semiconductor)) and (etch\$3 or implant\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:14
S12	12298	S11 and (resistor or resistance or resisting)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:14
S13	2829	S12 and (ion adj implant\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:14
S14	2383	S13 and mask	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:15

S15	908	S14 and (mask with expos\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:40
S16	2	S15 and (first adj type adj dop\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/06 21:16
S17	1300	438/301.ccls. or 438/510.ccls. or 438/514.ccls.	USPAT	OR	ON	2005/01/07 16:29
S18	5	((("6156602") or ("6103622") or ("6103621") or ("5924011") or ("5918119")).PN.	USPAT	OR	OFF	2005/01/07 16:29